

HMC506LP4 / 506LP4E

v01.0805



MMIC VCO w/ BUFFER AMPLIFIER, 7.8 - 8.7 GHz

Typical Applications

Low noise MMIC VCO w/Buffer Amplifier for:

- VSAT Radio
- Point to Point/Multipoint Radio
- Test Equipment & Industrial Controls
- Military End-Use

Features

Pout: +14 dBm

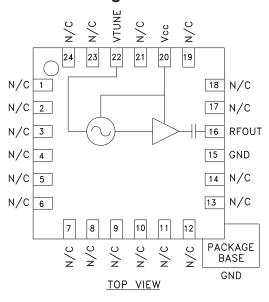
Phase Noise: -103 dBc/Hz @100 KHz

No External Resonator Needed

Single Supply: +3V @ 77 mA

QFN Leadless SMT Package, 16 mm²

Functional Diagram



General Description

The HMC506LP4 & HMC506LP4E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs with integrated resonators, negative resistance devices, varactor diodes, and buffer amplifiers. Covering 7.8 to 8.7 GHz, the VCO's phase noise performance is excellent over temperature, shock and vibration due to the oscillator's monolithic structure. Power output is +14 dBm typical from a single supply of +3.0V @ 77 mA. The voltage controlled oscillator is packaged in a leadless QFN 4 x 4 mm surface mount package.

Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, Vcc = +3V

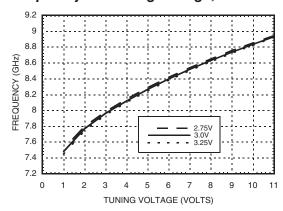
Parameter	Min.	Тур.	Max.	Units
Frequency Range	7.8 - 8.7		GHz	
Power Output	11.0	14.0		dBm
SSB Phase Noise @ 100 kHz Offset, Vtune= +5V @ RF Output		-103		dBc/Hz
Tune Voltage (Vtune)	1		11	V
Supply Current (Icc) (Vcc = +3.0V)		77		mA
Tune Port Leakage Current			10	μΑ
Output Return Loss		7		dB
Harmonics 2nd 3rd		-16 -28		dBc dBc
Pulling (into a 2.0:1 VSWR)		28		MHz pp
Pushing @ Vtune= +5V		78		MHz/V
Frequency Drift Rate		0.85		MHz/°C



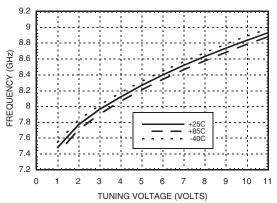


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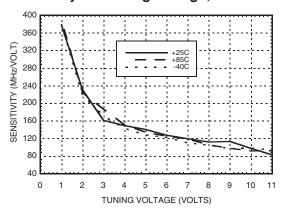
Frequency vs. Tuning Voltage, T= 25°C



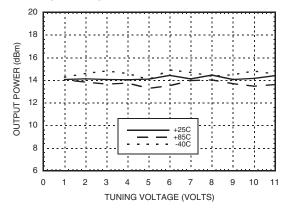
Frequency vs. Tuning Voltage, Vcc= +3V



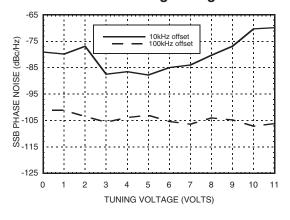
Sensitivity vs. Tuning Voltage, Vcc= +3V



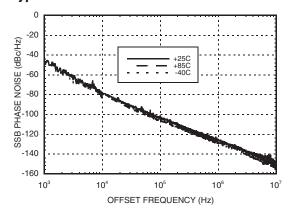
Output Power vs.
Tuning Voltage, Vcc= +3V



Phase Noise vs. Tuning Voltage



Typical SSB Phase Noise @ Vtune= +5V





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Absolute Maximum Ratings

Vcc	+3.5 Vdc	
Vtune	0 to +11V	
Channel Temperature	135 °C	
Continuous Pdiss (T = 85°C) (derate 6.07 mW/°C above 85°C)	303 mW	
Thermal Resistance (junction to ground paddle)	165 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	

Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)
2.75	66
3.0	77
3.25	88

Note: VCO will operate over full voltage range shown above.



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing

BOTTOM VIEW PIN 24 -.016 [0.40] REF 0.30 0.18 .008 [0.20] MIN 19 \cup \cup \cup \cup \cup PIN 1 HNNN XXXX 6 13 **EXPOSED** 12 LOT NUMBER GROUND PADDLE SQUARE 0.05 .002 1. LEADFRAME MATERIAL: COPPER ALLOY SEATING PLANE .003[0.08] C -c-

- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOT FOR SUGGESTED LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC506LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H506 XXXX
HMC506LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H506 XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX

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Pin Descriptions

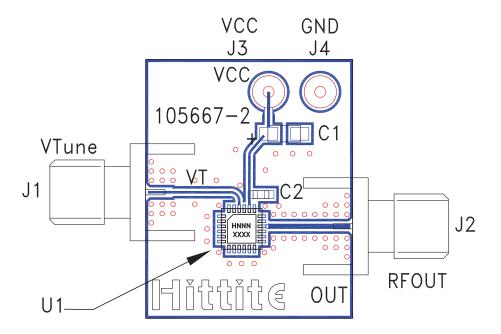
Pin Number	Function	Description	Interface Schematic
1- 14, 17 - 19, 21, 23, 24	N/C	No Connection	
15	GND	This pin must be connected to RF & DC ground.	○ GND =
16	RFOUT	RF output (AC coupled)	— —○ RFOUT
20	Vcc	Supply Voltage Vcc= 3V	Vcc O26pF
22	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	VTUNEO 5.2pF C;= 7.8pF
	GND	Package bottom has an exposed metal paddle that must be RF & DC grounded.	Ģ GND <u>=</u>





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Evaluation PCB



List of Materials for Evaluation PCB 105706 [1]

Item	Description	
J1 - J2	PCB Mount SMA RF Connector	
J3 - J4	DC Pin	
C1	4.7 μF Tantalum Capacitor	
C2	10,000 pF Capacitor, 0603 Pkg.	
U1	HMC506LP4 / HMC506LP4E VCO	
PCB [2]	105667 Eval Board	

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

^[2] Circuit Board Material: Rogers 4350



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Notes:

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